## NSN 5961-00-596-3297

Transistor - Page 1 of 1

A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-596-3297 **Inclosure Material:** Ceramic and metal **Overall Length:** 1.050 inches **Overall Height:** 0.280 inches **Overall Width:** 0.980 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 65.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 35.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 9.00 milliamperes source cutoff current and 30.00 milliamperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 117.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Internal metalization gold **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: